# NSN 5962-01-111-7480

Memory Microcircuit - Page 1 of 1



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## Features Provided:

Monolithic and programmable and 3-state output

## Inclosure Configuration:

Dual-in-line

## Output Logic Form:

Transistor-transistor logic

## Input Circuit Pattern:

9 input

## **Terminal Surface Treatment:**

Solder

## **Time Rating Per Chacteristic:**

70.00 nanoseconds propagation delay time, low to high level output

## Memory Device Type:

Rom

#### **Test Data Document:**

05869-726009-1 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

#### **Terminal Type And Quantity:**

16 printed circuit

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

#### Fiig:

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